

Supplementary Information

Room Temperature Ferromagnetism Properties of In<sub>2</sub>S<sub>3</sub> Nanoparticles Regulated by  
Doping with Gd ions

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Table S1. Various particle sizes of pristine  $\text{In}_2\text{S}_3$  and  $\text{In}_2\text{S}_3: \text{Gd}^{3+}$  samples.

Sample	$\beta_{\text{hkl}}$ (FWHM)	D (nm)
pristine $\text{In}_2\text{S}_3$	2.78	3.27
Gd doped $\text{In}_2\text{S}_3$ (0.39 at.%)	3.01	3.02
Gd doped $\text{In}_2\text{S}_3$ (1.20 at.%)	2.37	3.83
Gd doped $\text{In}_2\text{S}_3$ (1.68 at.%)	2.34	3.89
Gd doped $\text{In}_2\text{S}_3$ (2.17 at.%)	1.98	4.58

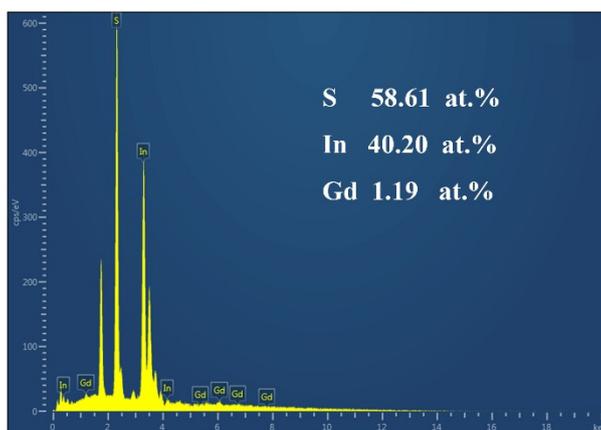


Figure S1. EDS pattern of the  $\text{In}_2\text{S}_3: \text{Gd}^{3+}$  (1.20 at.%) nanoparticles.

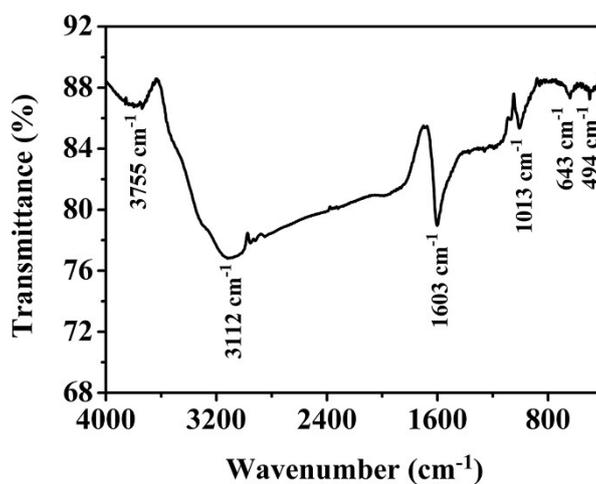


Figure S2. IR spectrum of the  $\text{In}_2\text{S}_3: \text{Gd}^{3+}$  (1.20 at.%) nanoparticles.

The IR spectrum of the  $\text{In}_2\text{S}_3: \text{Gd}^{3+}$  (1.20 at.%) nanoparticles is shown in Figure. S2, which is consistent with the reported results.<sup>1, 2</sup> The peaks at  $494 \text{ cm}^{-1}$  and  $643 \text{ cm}^{-1}$  may be caused by the mercaptoethanol absorbed on the surface of the  $\text{In}_2\text{S}_3: \text{Gd}^{3+}$

nanoparticles.<sup>3</sup> The peak at  $1013\text{ cm}^{-1}$  is ascribed to the C-O stretching vibration. The peak at  $1603\text{ cm}^{-1}$  can be attributed to  $\text{CO}_2$  absorbed on the surface of the  $\text{In}_2\text{S}_3: \text{Gd}^{3+}$  nanoparticles. The peak centered at  $3112\text{ cm}^{-1}$  corresponding to O-H stretching vibration which may be due to absorbed water molecules in the sample. The peak at  $3755\text{ cm}^{-1}$  is associated with the interaction of  $\text{In}^{3+}$ ,  $\text{S}^{2-}$  and  $\text{Gd}^{3+}$ . The results of IR spectrum further indicate that the dangling bonds on the surface can bond with some ions like  $(\text{O-H})^-$ ,  $\text{H}^+$  and  $(\text{HOCH}_2\text{CH}_2\text{S})^-$ , and these non-magnetic ions had no effect on the magnetism of the sample.

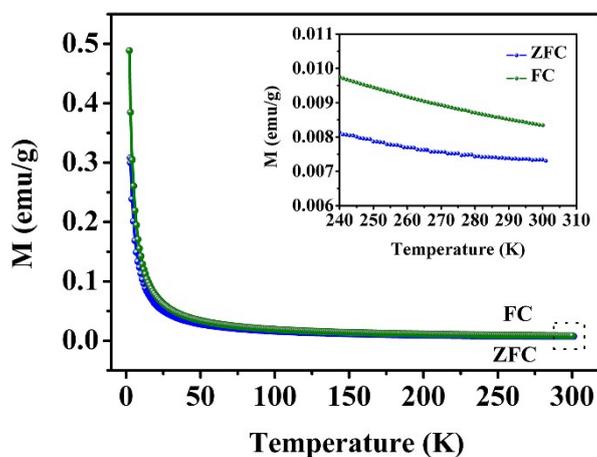


Figure S3. Temperature-dependent magnetization curves for the  $\text{In}_2\text{S}_3: \text{Gd}^{3+}$  (1.20 at.%) nanoparticles in ZFC and FC modes at a magnetic field of 500 Oe. The inset shows the high-magnification of the curves between 240 and 300 K.

Figure. S3 shows temperature-dependent magnetization curves for the  $\text{In}_2\text{S}_3: \text{Gd}^{3+}$  (1.20 at.%) nanoparticles in zero-field cooling (ZFC) and field cooling (FC) modes at a magnetic field of 500 Oe. Note that the ZFC-FC curves measured in the temperature range of 2-300K do not exhibit magnetic transition. The sharp increase of magnetization both in the ZFC-FC curves below 30 K and the presence of hysteresis at higher temperatures can be considered as ferromagnetic behavior. The small disparity between ZFC and FC curves indicates the existence of antiferromagnetic.<sup>4</sup>

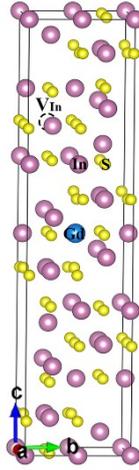


Figure S4. one In vacancy in a Gd doped  $\text{In}_2\text{S}_3$  system ( $\text{In}_{30}\text{GdS}_{48}$ ).

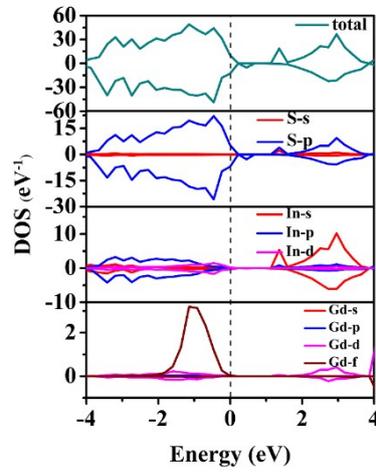


Figure S5. Spin-polarized total and partial DOS of one dopant Gd plus one vacancy defect ( $\text{In}_{30}\text{GdS}_{48}$ ).

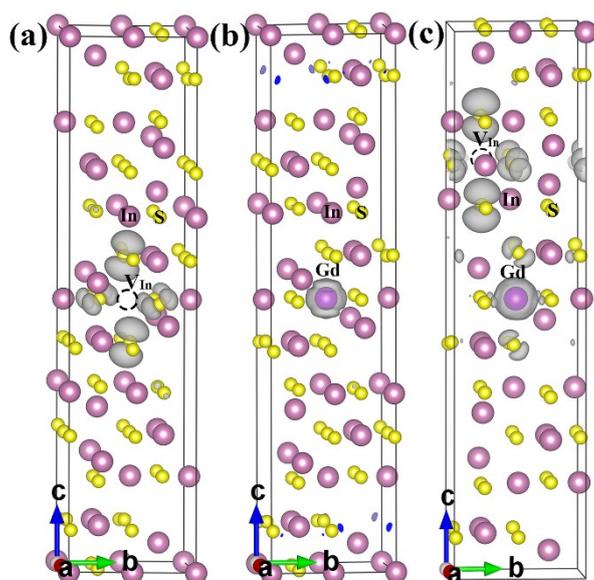


Figure S6. Spatial distribution of the spin density for (a)  $\text{In}_{31}\text{S}_{48}$  ( $\text{V}_{\text{In}}$ ), (b)  $\text{In}_{31}\text{Gd}_1\text{S}_{48}$  ( $\text{Gd}_{\text{In}}$ ) system, (c)  $\text{In}_{31}\text{Gd}_1\text{S}_{48}$  ( $\text{Gd}_{\text{In}}+\text{V}_{\text{In}}$ ) system. The black circle is the site of the removable In atom, the purple solid ball is the site of substituted Gd atom.

Table S2. The defect formation energies of  $\text{In}_{31}\text{S}_{48}$  and  $\text{In}_{30}\text{GdS}_{48}$  system under In-rich and S-rich conditions.

$E_f$	In-rich	S-rich
$\text{In}_{31}\text{S}_{48}$	4.992 eV	2.514 eV
$\text{In}_{30}\text{GdS}_{48}$	0.752 eV	-4.204 eV

## References

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